# Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# **HAT2173N**

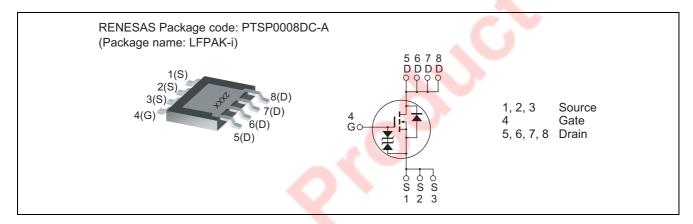
# Silicon N Channel Power MOS FET Power Switching

REJ03G1684-0100 Rev.1.00 May 28, 2008

### **Features**

- Capable of 8 V gate drive
- Low drive current
- High density mounting
- Low on-resistance  $R_{DS(on)} = 12.3 \text{ m}\Omega \text{ typ. (at } V_{GS} = 10 \text{ V})$

### **Outline**



# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	100	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	25	Α
Drain peak current	I <sub>D(pulse)</sub> Note1	100	Α
Body-drain diode reverse drain current	I <sub>DR</sub>	25	Α
Avalanche current	I <sub>AP</sub> Note 2	25	Α
Avalanche energy	E <sub>AR</sub> Note 2	62.5	mJ
Channel dissipation	Pch Note3	30	W
Channel to case thermal resistance	θch-C	4.17	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\propto$ s, duty cycle  $\leq$  1%

2. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

3.  $Tc = 25^{\circ}C$ 

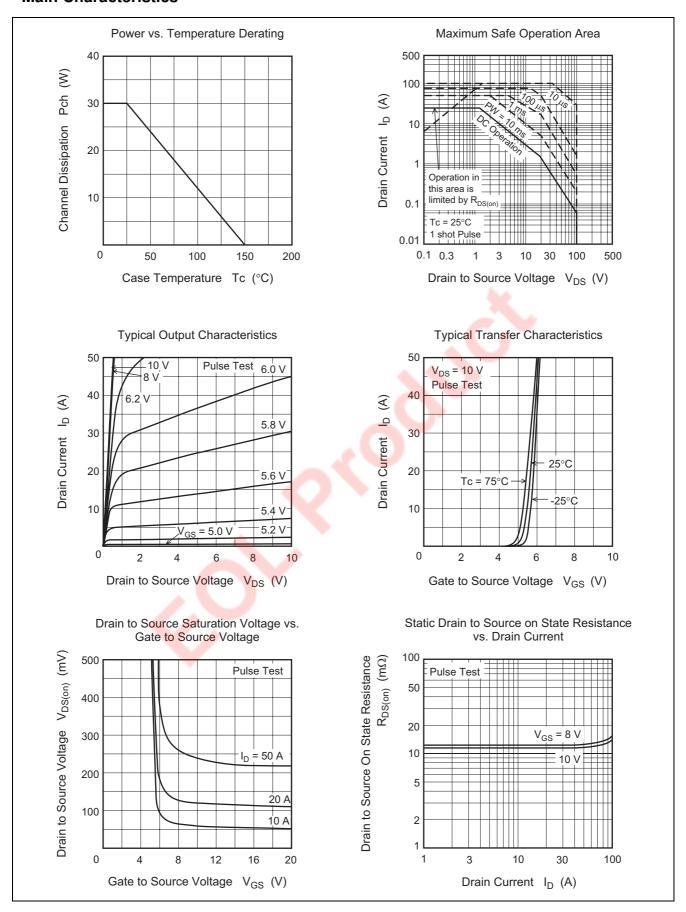
# **Electrical Characteristics**

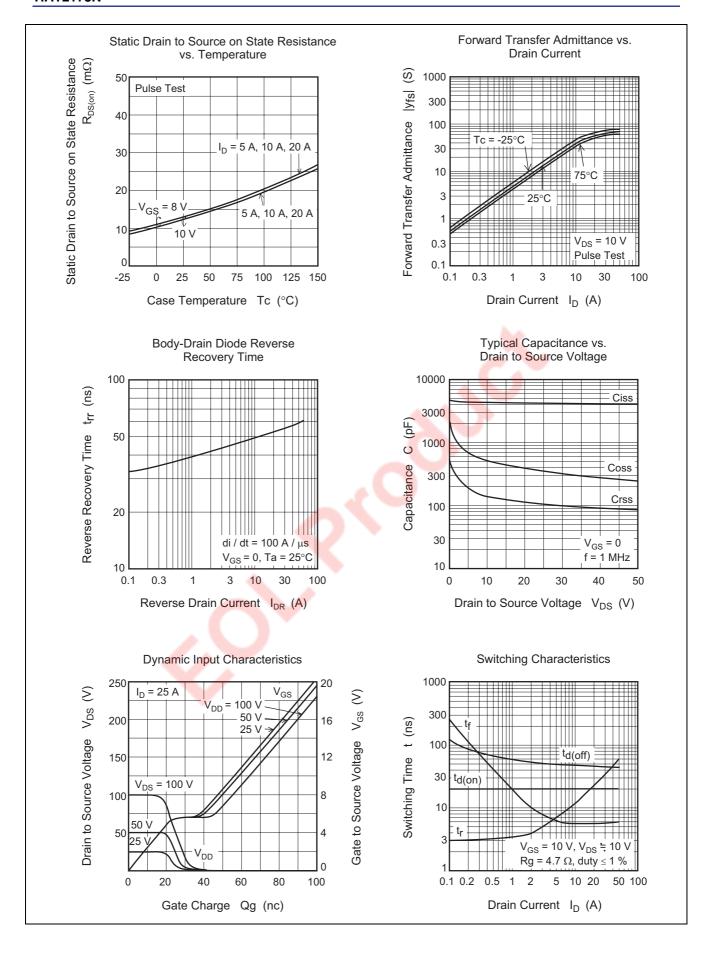
 $(Ta = 25^{\circ}C)$ 

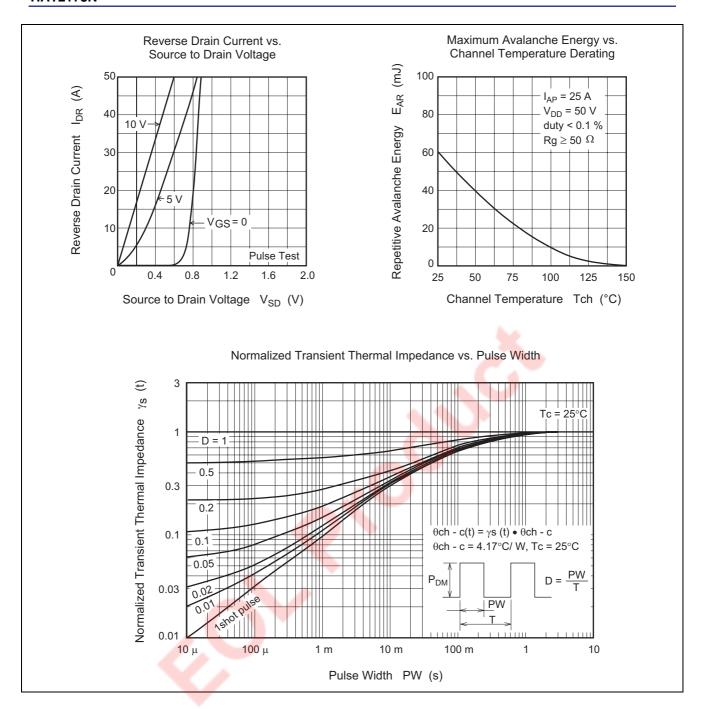
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	100			٧	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20			٧	$I_G = \pm 100 \propto A, V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_		±10	∝A	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_		1	∝A	$V_{DS} = 40 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	4.0		6.0	>	$V_{DS} = 10 \text{ V}, I_D = 20\text{mA}$
Static drain to source on state	R <sub>DS(on)</sub>	_	12.3	15.3	mΩ	$I_D = 12.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R <sub>DS(on)</sub>	_	13.3	17.8	mΩ	$I_D = 12.5 \text{ A}, V_{GS} = 8 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y <sub>fs</sub>	27	45		S	$I_D = 12.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	4350		pF	$V_{DS} = 10 \ V, V_{GS} = 0,$
Output capacitance	Coss	_	520		рF	f = 1 MHz
Reverse transfer capacitance	Crss	_	150	_	рF	
Gate resistance	Rg	_	0.5	_	Ω	
Total gate charge	Qg	_	61	_	nC	$V_{DD} = 50 \text{ V}, V_{GS} = 10 \text{ V},$
Gate to source charge	Qgs	_	23	_	nC	$I_D = 25 A$
Gate to drain charge	Qgd	_	14.5	_	nC	
Turn-on delay time	t <sub>d(on)</sub>	_	20	_	ns	$V_{GS} = 10 \text{ V}, I_D = 12.5 \text{ A},$
Rise time	t <sub>r</sub>	_	15	_	ns	$V_{DD} \cong 30 \text{ V}, R_L = 2.4 \Omega,$
Turn-off delay time	$t_{d(off)}$	_	37		ns	$Rg = 4.7 \Omega$
Fall time	t <sub>f</sub>	_	5.7	1	ns	
Body-drain diode forward voltage	$V_{DF}$	_	0.82	1.07	V	$I_F = 25 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery	t <sub>rr</sub>	_	55		ns	$I_F = 25 \text{ A}, V_{GS} = 0$
time						$di_F/dt = 100 \text{ A}/ \infty \text{s}$

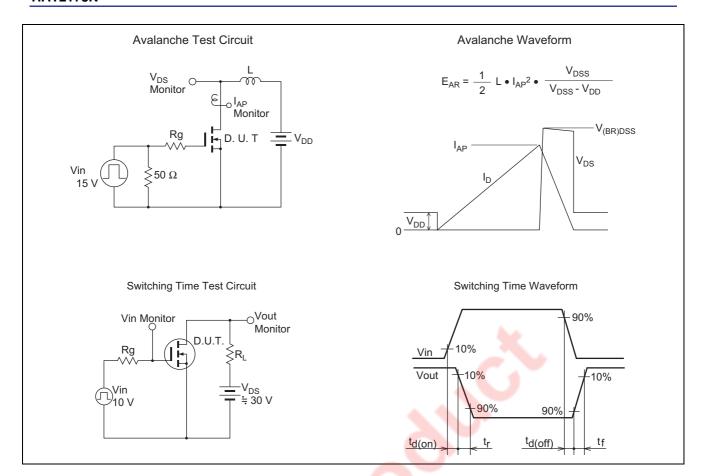
Notes: 4. Pulse test

### **Main Characteristics**

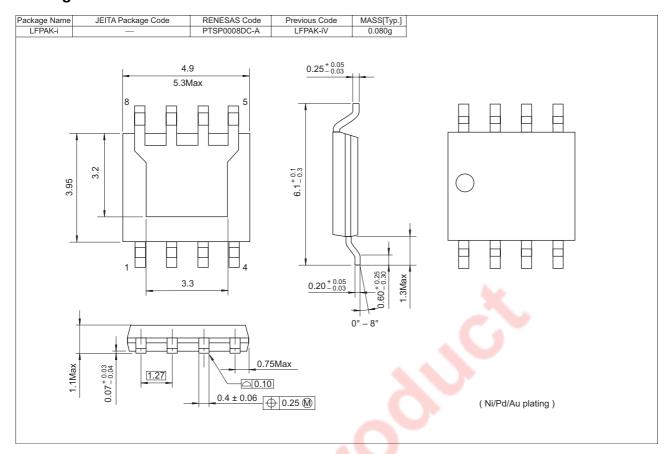








# **Package Dimensions**



# **Ordering Information**

Part No.	Quantity	Shipping Container
HAT2173N-EL-E	2500 pcs	Taping

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